NSN 5961-00-450-8531

Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.190 inches
Terminal Length:
0.500 inches
Overall Diameter:
0.219 inches
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Gate
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
30.0 breakover voltage, dc
Current Rating Per Characteristic:
0.20 amperes source cutoff current
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: pnpn
Terminal Type And Quantity:
3 uninsulated wire lead
Specification Data:
80131-release5472 professional/industrial association specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:

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